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Performance of vapor-diffused Nb₃Sn grown on Nb

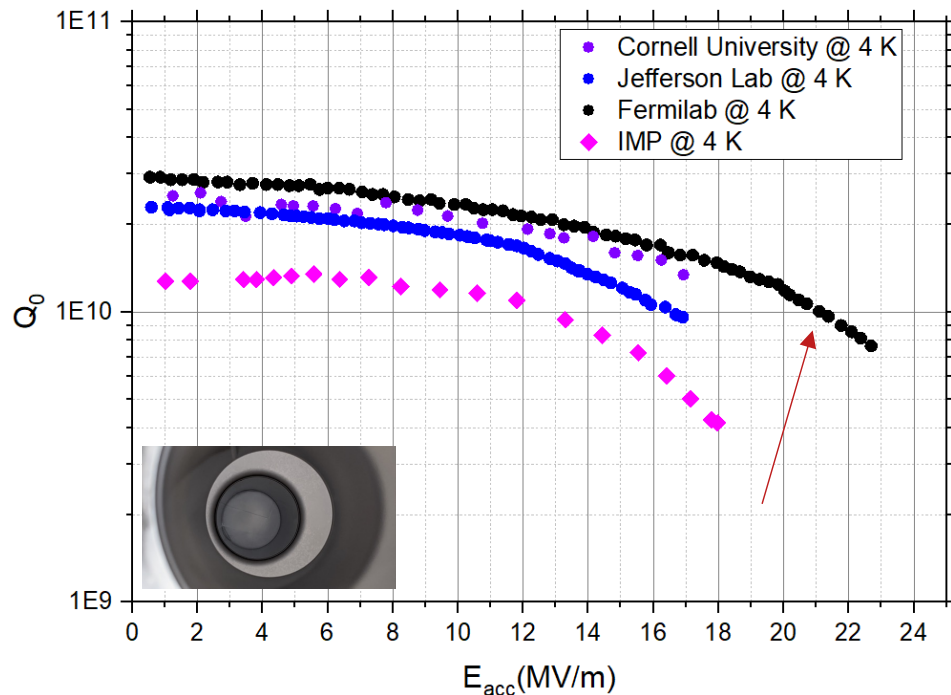
Uttar Pudasaini

Sunday, December 3, 2023

 **Jefferson Lab**

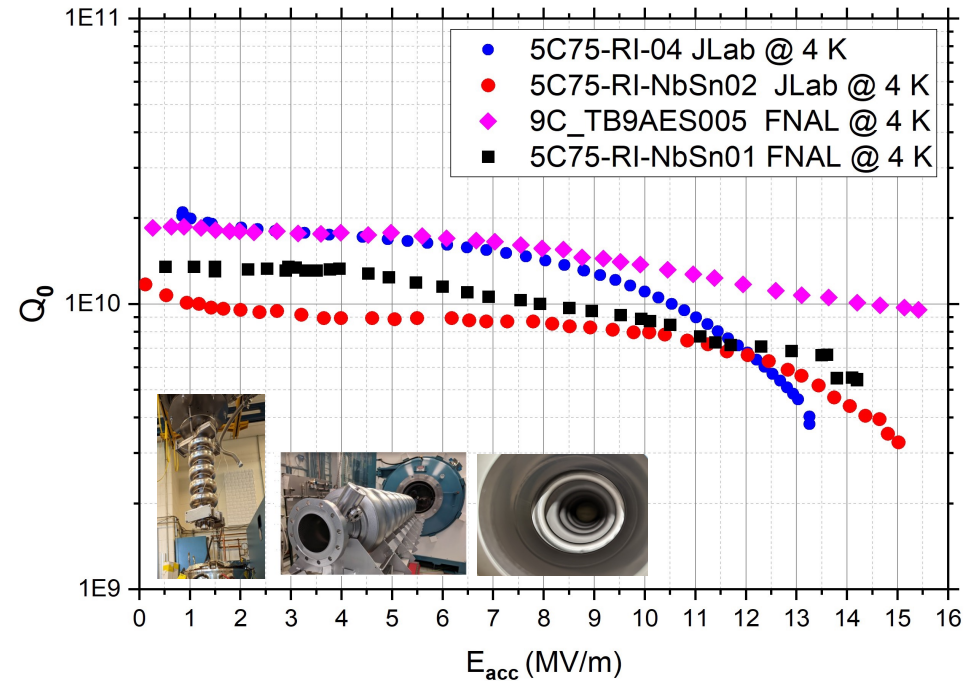
Performance of vapor-diffused Nb₃Sn grown on Nb

R&D 1.3/1.5 GHz single-cell cavity performance



- 1.3/1.5 GHz single-cell cavities attain accelerating gradient in excess of 20 MV/m with $Q \sim 10^{10}$.
- Cavities of various frequencies (650 MHz, 952 MHz, 2.6 GHz, 3.6 GHz) coated at different facilities show comparable performance.
- 952 MHz and 650 MHz cavities successfully operated with cryocoolers.

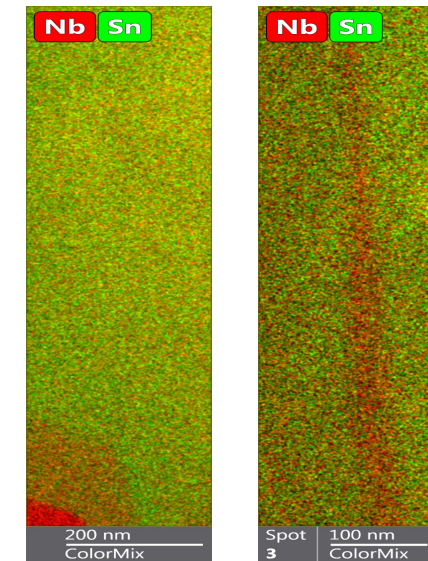
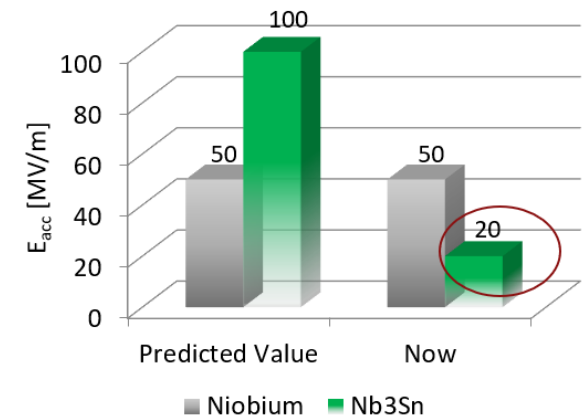
Multi-cell cavity performance



- 1.5 GHz five-cell and 1.3 GHz 9-cell cavities were demonstrated to reach $Q \sim 10^{10}$ at 10 MV/m at 4.4 K.
- Maximum gradients achieved up to ~ 20 MV/m.
- Several projects are underway to build cryomodules with coated cavities aiming for 4 K operation with conduction cooling.

Vapor-diffused Nb₃Sn grown on Nb: current issues

- Why is the attainable gradient limited?
 - Several approaches are being explored to push the gradient.
 - Roughness/Topography Management: Parameter optimization post-coating treatment and deposition of Sn before thermal diffusion.....
 - Film thickness reduction: correlates with surface roughness reduction and improved gradient limit
 - What are the other limiting factors?
- What causes the frequent Q-slope?
 - Studies are focused on correlating material properties and RF performance
 - Grain boundary structure and compositions
 - Limitations due to local defects
 - Facility and procedure dependent: performance sensitivity to Sn residue condensation, Ti evaporation from NbTi flanges....?
- Feasibility for practical applications – how to preserve thin-film performance?
 - The coating process is adopted for larger/longer cavities with multiple Sn sources and coating parameter modifications.
 - How to deposit a high-quality coating on any arbitrary shape/sized cavities?
 - NbTi flanges are more practical – avoid Ti contaminations
 - Hardware to contain Ti and/or altering coating parameters?



TEM analysis of grain boundaries with and without Q-slope

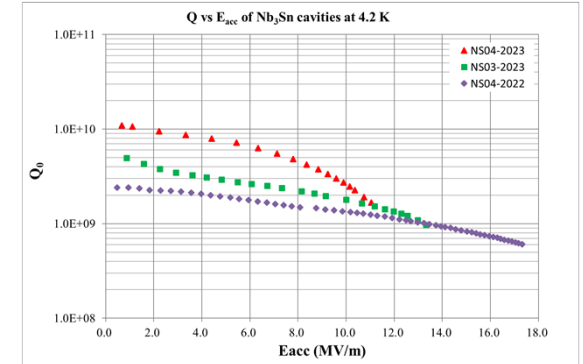
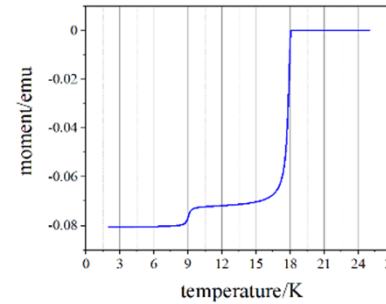
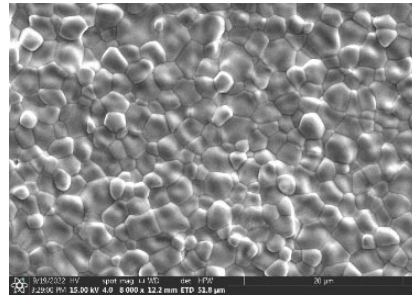
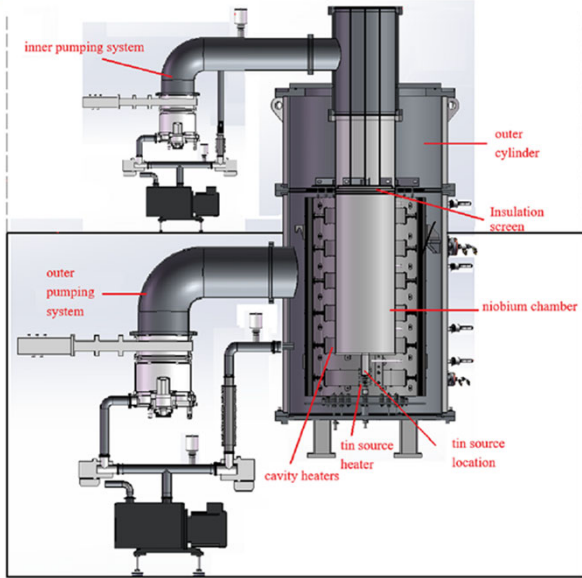
- Reproducibility is challenging!??

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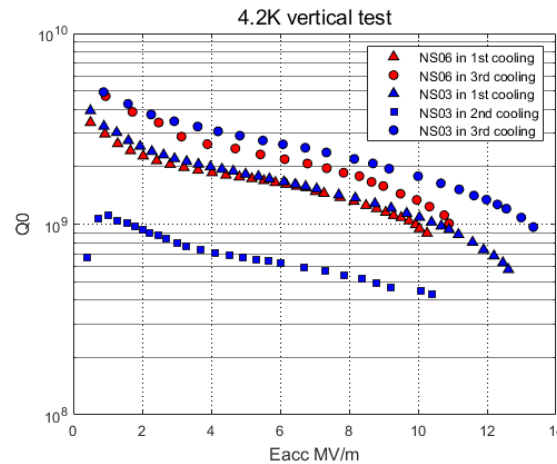
Nb₃Sn Cavities Coated by Tin Vapor Diffusion (Jiankui Hao, PKU)



Coating: 1250°C, 120 min, Annealing: 1150 °C, 60 min
 $Q_0 \sim 1.1 \times 10^{10}$ @4.2K @ low field, max. $E_{acc} \sim 17.3$ MV/m



3 tin sources

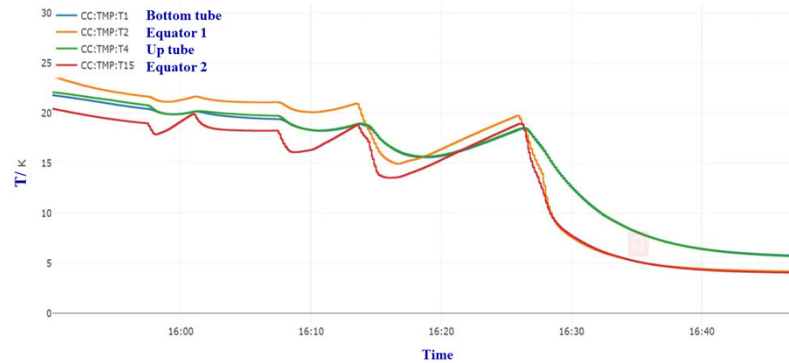
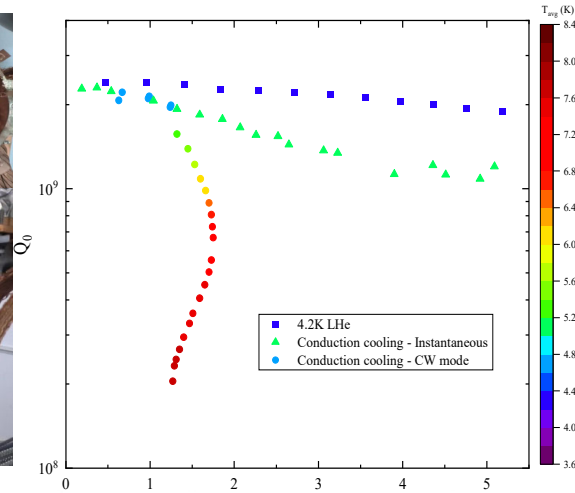
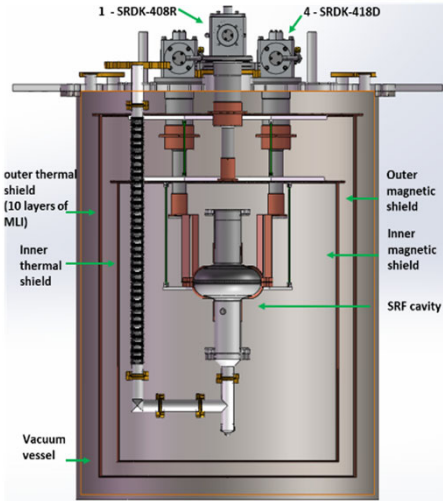


Vertical tests at different cooling rate

Vertical Tests (2023)	T grad., cooling rate	Q_0 @ ~1.0 MV/m
NS03(1 st , Oct. 17)	15.7 K/m, ~6 min/K	3.3E9
NS06(1 st , Oct. 17)	15.7 K/m	3.0E9
NS03(2 nd , Oct. 18)	110	1.1E9
NS03(3 rd , Oct. 23)	2.7 K/m, ~10 min/K	4.9E9
NS06(3 rd , Oct. 23)	2.7	4.7E9



Conduction cooling of Nb₃Sn cavity



Cryocooler on and off, 17-18 K, $\Delta T < 2$ K
 $T < 16$ K, cryocooler on, cooling down to 4 K

Nb₃Sn cavity
 Conduction cooling

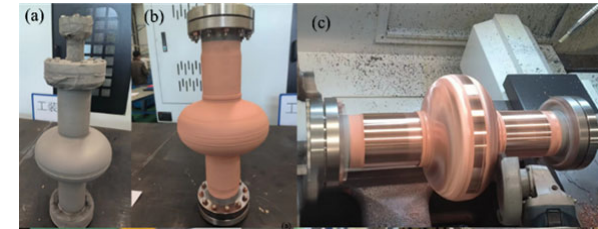
$$Q_0 \sim 7E8$$

$$@ E_{acc} = 1.75 \text{ MV/m}$$

$$P_c = 0.57 \text{ W}$$

Next step

- Choose the best Nb₃Sn cavity NS04
- Cold spray with copper
- Slower cooling controlled with heater



(a) sandblasted (b) cold sprayed
 (c) mechanical polished

Question/Discussion

- What's the best cooling rate for vertical test and conduction cooling?

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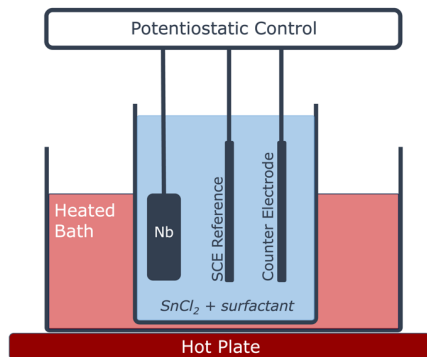
Goal for conduction-cooled SRF cavity technology: Reach higher Q_0 at 4.2K

Main challenge: achieve a smooth Nb₃Sn film with uniform thickness and stoichiometry

→ Improving vapor diffusion:

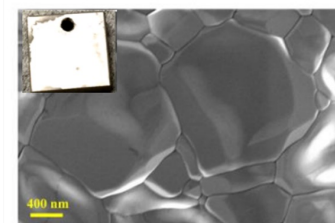
sample studies have shown that pre-nucleation chemical treatments affect tin coverage on Nb substrate

→ Alternative growth method: electrochemical synthesis

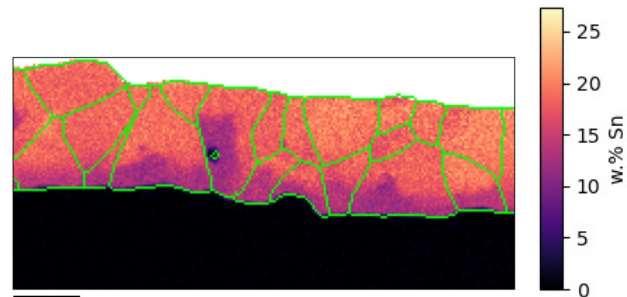


Electrochemical deposition

Anneal > 900°C to thermally convert to stoichiometric, smooth Nb₃Sn

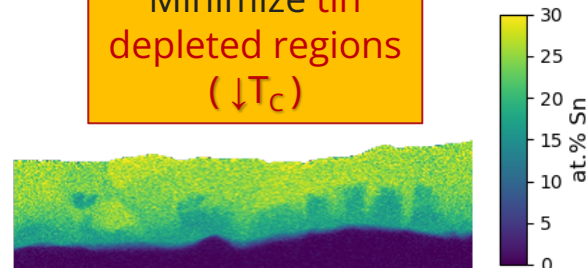


Lower surface roughness



1 μm

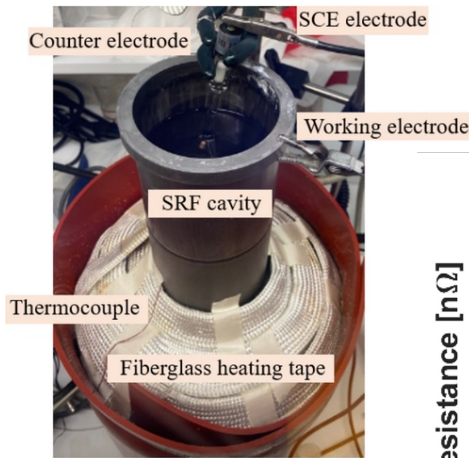
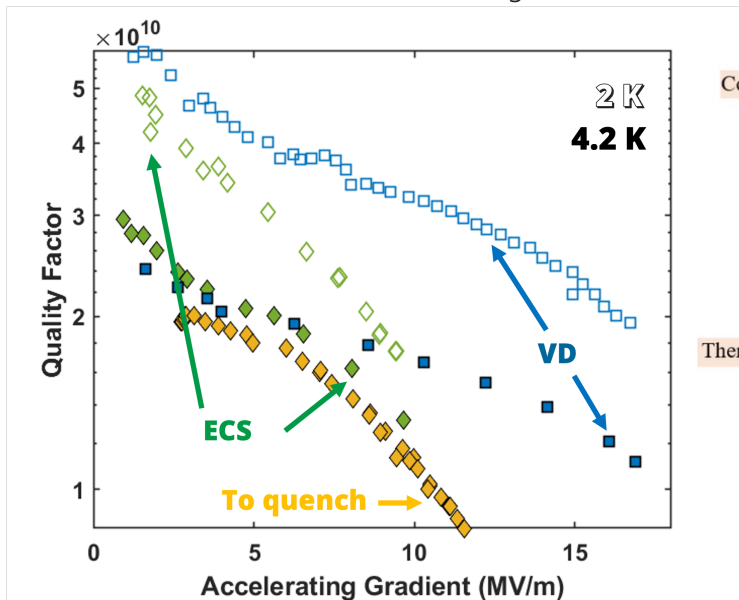
Minimize tin depleted regions (↓T_c)



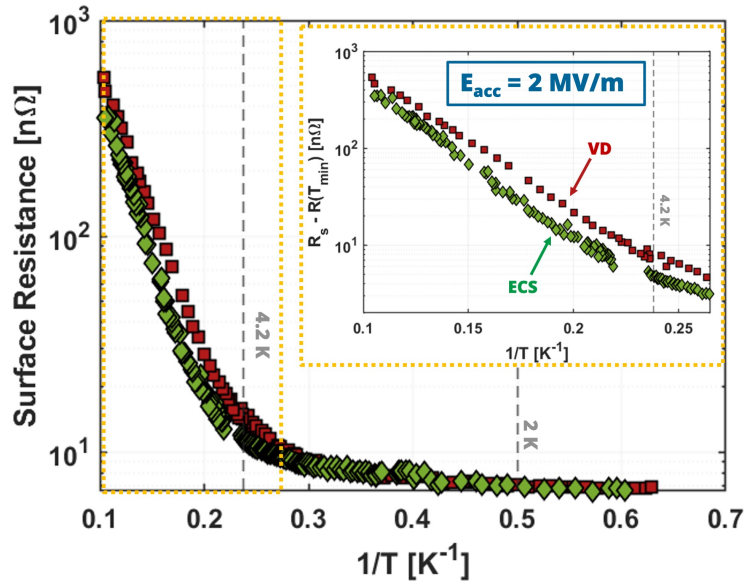
Z. Sun et al 2023 Supercond. Sci. Technol. **36** 115003
DOI 10.1088/1361-6668/acf5ab

Proof of Principle: Electrochemical Synthesis

This alternative growth method provides **uniform tin nucleation** and **sufficient Sn supply** in critical times
⇒ **smoother** Nb₃Sn films with **little variation in Sn concentration with depth**.



→ Very low BCS low resistance



→ First ever alternative growth method to vapor diffusion to achieve **quality factors $>10^{10}$** at **4.2 K**